Diode Semiconductor Device - Page 1 of 1



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Inclosure	Material:
Glass	
Overall Le	ength:
0.281 inch	les
Terminal	Length:
1.000 inch	les
Overall D	iameter:
0.110 inch	les
Mounting	Method:
Terminal	
Features	Provided:
Hermetica	Ily sealed case
Semicond	ductor Material:
Silicon	
Voltage R	ating In Volts Per Characteristic:
400.0 rev	erse voltage, peak
Current R	ating Per Characteristic:
1.00 ampe	eres forward current, average absolute
Maximum	Operating Tempurature Per Measurement Point:
150.0 deg	rees celsius ambient air
Terminal	Type And Quantity:
2 uninsula	ted wire lead
Shelf Life	:
N/a	
Unit Of M	easure:
Demilitari	zation:
No	
Fiig:	
A110a0	